

3.3 V, Full-Duplex, 840 μ A, 20 Mbps, EIA RS-485 Transceiver

ADM3491

FEATURES

Operates with 3.3 V supply
EIA RS-422 and RS-485 compliant over full CM range
19 kΩ input impedance
Up to 50 transceivers on bus
20 Mbps data rate
Short circuit protection
Specified over full temperature range
Thermal shutdown
Interoperable with 5 V logic
840 μA supply current
2 nA shutdown current
Also available in TSSOP package
Meets IEC1000-4-4 (>1 kV)
8 ns skew

APPLICATIONS

Telecommunications
DTE-DCE interface
Packet switching
Local area networks
Data concentration
Data multiplexers
Integrated services digital network (ISDN)
AppleTalk
Industrial controls

Upgrade for MAX 3491, SN75ALS180

GENERAL DESCRIPTION

The ADM3491 is a low power, differential line transceiver designed to operate using a single 3.3 V power supply. Low power consumption, coupled with a shutdown mode, makes it ideal for power-sensitive applications. It is suitable for communication on multipoint bus transmission lines.

FUNCTIONAL BLOCK DIAGRAM

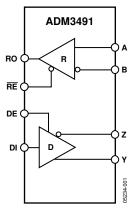


Figure 1.

The ADM3491 is intended for balanced data transmission and complies with both EIA Standards RS-485 and RS-422. It contains a differential line driver and a differential line receiver, making it suitable for full-duplex data transfer.

The input impedance is $19 \, k\Omega$, allowing up to 50 transceivers to be connected on the bus. Excessive power dissipation caused by bus contention or by output shorting is prevented by a thermal shutdown circuit. This feature forces the driver output into a high impedance state, if a significant temperature increase is detected in the internal driver circuitry during fault conditions.

The receiver contains a fail-safe feature that results in a logic high output state, if the inputs are unconnected (floating).

The ADM3491 is fabricated on BiCMOS, an advanced mixed technology process combining low power CMOS with fast switching bipolar technology.

The ADM3491 is fully specified over the industrial temperature range and is available in DIP and SOIC packages, as well as the space-saving TSSOP package.

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REVISION HISTORY

11/04—Rev. 0 to Rev. A

Format Updated	Universal
Changes to Specifications Section	3
Changes to Ordering Guide	13

1/98—Revision 0: Initial Version

SPECIFICATIONS

 V_{CC} = 3.3 V \pm 0.3 V. All specifications T_{MIN} to T_{MAX} unless otherwise noted.

Table 1.

Parameter	Min	Тур	Max	Unit	Test Conditions/Comments
DRIVER					
Differential Output Voltage, VoD	2.0			V	RL = 100Ω , Figure 4, $V_{CC} > 3.1 V$
	1.5			V	RL = 54Ω , Figure 4
	1.5			V	RL = 60 Ω, Figure 5, $-7 \text{ V} < \text{V}_{TST} < +12 \text{ V}$
$\Delta V_{OD} $ for Complementary Output States			0.2	V	$R = 54 \Omega$ or 100 Ω, Figure 4
Common-Mode Output Voltage, Voc			3	V	$R = 54 \Omega$ or 100 Ω , Figure 4
$\Delta V_{OC} $ for Complementary Output States			0.2	V	$R = 54 \Omega$ or 100 Ω, Figure 4
CMOS Input Logic Threshold Low, V _{INL}			8.0	V	
CMOS Input Logic Threshold High, VINH	2.0			V	
Logic Input Current (DE, DI, RE)			±1.0	μΑ	
Output Leakage (Y, Z) Current			±3	μΑ	$V_0 = -7 \text{ V or } +12 \text{ V}, V_{CC} = 0 \text{ V or } 3.6 \text{ V}$
Output Short-Circuit Current			±250	mA	$V_0 = -7 \text{ V or } +12 \text{ V}$
RECEIVER					
Differential Input Threshold Voltage, V _™	-0.2		+0.2	V	$-7 \text{ V} < \text{V}_{\text{CM}} < +12 \text{ V}$
Input Voltage Hysteresis, ∆V _{TH}		50		mV	$V_{CM} = 0 V$
Input Resistance	12	19		kΩ	$-7 \text{ V} < \text{V}_{\text{CM}} < +12 \text{ V}$
Input Current (A, B)			1	mA	V _{IN} = 12 V
			-0.8	mA	$V_{IN} = -7 \text{ V}$
Logic Enable Input Current (RE)			±1	μΑ	
Output Voltage Low, Vol			0.4	V	I _{OUT} = 2.5 mA
Output Voltage High, V _{OH}	V _{CC} – 0.4 V			V	$I_{OUT} = -1.5 \text{ mA}$
Short-Circuit Output Current			±60	mA	$V_{OUT} = GND \text{ or } V_{CC}$
Three-State Output Leakage Current			±1.0	μΑ	$V_{CC} = 3.6 \text{ V}, 0 \text{ V} < V_{OUT} < V_{CC}$
POWER SUPPLY CURRENT					
I _{cc}					Outputs unloaded
		0.84	1.5	mA	$DE = V_{CC}$, $\overline{RE} = 0 \text{ V}$
		0.84	1.5	mA	$DE = 0 V, \overline{RE} = 0 V$
Supply Current in Shutdown		0.002	1	μΑ	$DE = 0 V, \overline{RE} = V_{CC}$

TIMING SPECIFICATIONS

 V_{CC} = 3.3 V, T_A = 25°C.

Table 2.

Parameter	Min	Тур	Max	Unit	Test Conditions/ Comments	
DRIVER						
Differential Output Delay, TDD	1		35	ns	$R_L = 60 \Omega$, $C_{L1} = C_{L2} = 15 \text{ pF}$, Figure 8	
Differential Output Transition Time	1	8	15	ns	$R_L = 60 \Omega$, $C_{L1} = C_{L2} = 15 \text{ pF}$, Figure 8	
Propagation Delay Input to Output, TPLH, TPHL	7	22	35	ns	$R_L = 27 \Omega$, $C_{L1} = C_{L2} = 15 \text{ pF}$, Figure 9	
Driver Output to Output, Tskew			8	ns	$R_L = 54 \Omega$, $C_{L1} = C_{L2} = 15 \text{ pF}$, Figure 9	
ENABLE/DISABLE						
Driver Enable to Output Valid		45	90	ns	$R_L = 110 \Omega$, $C_L = 50 pF$, Figure 6	
Driver Disable Timing		40	80	ns	$R_L = 110 \Omega$, $C_L = 50 pF$, Figure 6	
Driver Enable from Shutdown		650	110	ns	$R_L = 110 \Omega$, $C_L = 15 pF$, Figure 6	
RECEIVER						
Time to Shutdown	80	190	300	ns		
Propagation Delay Input to Output, TPLH, TPHL	25	65	90	ns	C _L = 15 pF, Figure 11	
Skew, T _{PLH} – T _{PHL}			10	ns	C _L = 15 pF, Figure 11	
Receiver Enable, T _{EN}		25	50	ns	C _L = 15 pF, Figure 7	
Receiver Disable, T _{DEN}		25	45	ns	$C_L = 15 \text{ pF, Figure 7}$	
Receiver Enable from Shutdown			500	ns	C _L = 15 pF, Figure 7	

 $V_{\rm CC}$ = 3.3 V \pm 0.3 V, $T_{\rm A}$ = $T_{\rm MIN}$ to $T_{\rm MAX}.$

Table 3.

Parameter	Min	Тур	Max	Unit	Test Conditions/ Comments	
DRIVER						
Differential Output Delay, TDD	1		70	ns	$R_L = 60 \Omega$, $C_{L1} = C_{L2} = 15 \text{ pF}$, Figure 8	
Differential Output Transition Time	2	8	15	ns	$R_L = 60 \Omega$, $C_{L1} = C_{L2} = 15 \text{ pF}$, Figure 8	
Propagation Delay Input to Output, T _{PLH} , T _{PHL}	7	22	70	ns	$R_L = 27 \Omega$, $C_{L1} = C_{L2} = 15 pF$, Figure 9	
Driver Output to Output, T _{SKEW}			10	ns	$R_L = 54 \Omega$, $C_{L1} = C_{L2} = 15 pF$, Figure 9	
ENABLE/DISABLE						
Driver Enable to Output Valid		45	110	ns	$R_L = 110 \Omega$, $C_L = 50 pF$, Figure 6	
Driver Disable Timing		40	110	ns	$R_L = 110 \Omega$, $C_L = 50 pF$, Figure 6	
Driver Enable from Shutdown		650	110	ns	$R_L = 110 \Omega$, $C_L = 15 pF$, Figure 6	
RECEIVER						
Time to Shutdown	50	190	500	ns		
Propagation Delay Input to Output, TPLH, TPHL	25	65	115	ns	C _L = 15 pF, Figure 11	
Skew, T _{PLH} – T _{PHL}			20	ns	C _L = 15 pF, Figure 11	
Receiver Enable, T _{EN}		25	50	ns	C _L = 15 pF, Figure 7	
Receiver Disable, T _{DEN}		25	50	ns	$C_L = 15 \text{ pF, Figure 7}$	
Receiver Enable from Shutdown			600	ns	C _L = 15 pF, Figure 7	

ABSOLUTE MAXIMUM RATINGS

 $T_A = 25$ °C, unless otherwise noted.

Table 4.

ParameterMinVcc7 VInputs-0.3 V to Vcc + 0.3 VDriver Input (DI)-0.3 V to Vcc + 0.3 VControl Inputs (DE, RE)-0.3 V to Vcc + 0.3 VReceiver Inputs (A, B)-7.5 V to +12.5 VOutputs-7.5 V to +12.5 VDriver Output-0.5 V to Vcc + 0.5 V14-Lead DIP, Power Dissipation800 mWθJA, Thermal Impedance140°C/W14-Lead SOIC, Power Dissipation650 mWθJA, Thermal Impedance115°C/W16-Lead TSSOP, Power Dissipation500 mWθJA, Thermal Impedance158°C/WOperating Temperature Range-40°C to +85°CIndustrial (A Version)-40°C to +85°CStorage Temperature Range-65°C to +150°CLead Temperature (Soldering, 10 s)300°CVapor Phase (60 s)215°CInfrared (15 s)220°CESD Rating>2 kVEFT Rating (IEC1000-4-4)>1 kV	1 avic 4.	
Inputs Driver Input (DI) Control Inputs (DE, RE) Receiver Inputs (A, B) Outputs Driver Outputs Receiver Output 14-Lead DIP, Power Dissipation Θ _{JA} , Thermal Impedance 16-Lead TSSOP, Power Dissipation Θ _{JA} , Thermal Impedance 16-Lead TSSOP, Power Dissipation Θ _{JA} , Thermal Impedance 115°C/W 16-Lead TSSOP, Power Dissipation Θ _{JA} , Thermal Impedance 115°C/W 500 mW 5	Parameter	Min
Driver Input (DI) Control Inputs (DE, RE) Receiver Inputs (A, B) Outputs Driver Outputs Priver Outputs Receiver Output 14-Lead DIP, Power Dissipation Θ _{JA} , Thermal Impedance 16-Lead TSSOP, Power Dissipation Θ _{JA} , Thermal Impedance 16-Lead TSSOP, Power Dissipation Θ _{JA} , Thermal Impedance 115°C/W 158°C/W 158°C/W 0perating Temperature Range Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating	Vcc	7 V
Control Inputs (DE, RE) Receiver Inputs (A, B) Outputs Driver Outputs Receiver Output 14-Lead DIP, Power Dissipation θ_{JA} , Thermal Impedance 16-Lead TSSOP, Power Dissipation θ_{JA} , Thermal Impedance 16-Lead TSSOP, Power Dissipation θ_{JA} , Thermal Impedance 115°C/W 109rating Temperature Range Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating -0.3 V to Vcc + 0.3 V -7.5 V to +12.5 V -0.5 V to +12.5 V 800 mW 140°C/W 550 mW 158°C/W 500 mW 158°C/W 220°C 220°C >2 kV	Inputs	
Receiver Inputs (A, B) Outputs Driver Outputs Receiver Output 14-Lead DIP, Power Dissipation θ _{JA} , Thermal Impedance 14-Lead SOIC, Power Dissipation θ _{JA} , Thermal Impedance 16-Lead TSSOP, Power Dissipation θ _{JA} , Thermal Impedance 16-Lead TSSOP, Power Dissipation θ _{JA} , Thermal Impedance 158°C/W Operating Temperature Range Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating -7.5 V to +12.5 V -0.5 V to +12.5 V -0.5 V to Vcc + 0.5 V 800 mW 140°C/W 158°C/W -500 mW -40°C to +85°C -65°C to +150°C 220°C >2 kV	Driver Input (DI)	$-0.3 \text{ V to V}_{CC} + 0.3 \text{ V}$
Outputs Driver Outputs Receiver Output 14-Lead DIP, Power Dissipation Θ _{JA} , Thermal Impedance 14-Lead TSSOP, Power Dissipation Θ _{JA} , Thermal Impedance 16-Lead TSSOP, Power Dissipation Θ _{JA} , Thermal Impedance 15°C/W 16-Lead TSSOP, Power Dissipation Θ _{JA} , Thermal Impedance 158°C/W Operating Temperature Range Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating -7.5 V to +12.5 V -0.5 V to Vcc + 0.5 V 800 mW 15°C/W 550 mW 158°C/W 250°C 250°C 220°C 220°C 220°C	Control Inputs (DE, RE)	$-0.3 \text{ V to V}_{CC} + 0.3 \text{ V}$
Driver Outputs Receiver Output 14-Lead DIP, Power Dissipation θ _{JA} , Thermal Impedance 140°C/W 14-Lead TSSOP, Power Dissipation θ _{JA} , Thermal Impedance 115°C/W 16-Lead TSSOP, Power Dissipation θ _{JA} , Thermal Impedance 158°C/W Operating Temperature Range Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating -0.5 V to +12.5 V -0.5 V to +0.5 V 800 mW 140°C/W 550 mW 500	Receiver Inputs (A, B)	–7.5 V to +12.5 V
Receiver Output 14-Lead DIP, Power Dissipation θ _{JA} , Thermal Impedance 14-Lead SOIC, Power Dissipation θ _{JA} , Thermal Impedance 16-Lead TSSOP, Power Dissipation θ _{JA} , Thermal Impedance 15°C/W 500 mW 500 mW 158°C/W Operating Temperature Range Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating -0.5 V to Vcc + 0.5 V 800 mW 140°C/W 500 mW 158°C/W 500 mW 158°C/W 215°C 220°C >2 kV	Outputs	
14-Lead DIP, Power Dissipation θ _{JA} , Thermal Impedance 14-Lead SOIC, Power Dissipation θ _{JA} , Thermal Impedance 115°C/W 16-Lead TSSOP, Power Dissipation θ _{JA} , Thermal Impedance 158°C/W Operating Temperature Range Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating 800 mW 140°C/W 158°C/W 500 mW 115°C/W 500 mW 158°C/W 500 mW 1	Driver Outputs	−7.5 V to +12.5 V
 θ_{JA}, Thermal Impedance 140°C/W 14-Lead SOIC, Power Dissipation θ_{JA}, Thermal Impedance 115°C/W 16-Lead TSSOP, Power Dissipation θ_{JA}, Thermal Impedance Operating Temperature Range Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating 140°C/W 500 mW 158°C/W 300 mV -40°C to +85°C -65°C to +150°C 220°C >2 kV 	Receiver Output	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
14-Lead SOIC, Power Dissipation θ _{JA} , Thermal Impedance 16-Lead TSSOP, Power Dissipation θ _{JA} , Thermal Impedance 158°C/W Operating Temperature Range Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating 650 mW 115°C/W 500 mW 158°C/W 300 mV 158°C/W 250°C 240°C 220°C 220°C 220°C 220°C	14-Lead DIP, Power Dissipation	800 mW
 θ_{JA}, Thermal Impedance 16-Lead TSSOP, Power Dissipation θ_{JA}, Thermal Impedance Operating Temperature Range Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating 115°C/W 500 mW 158°C/W 300°C 215°C 220°C >2 kV 	θ_{JA} , Thermal Impedance	140°C/W
16-Lead TSSOP, Power Dissipation θ _{JA} , Thermal Impedance Operating Temperature Range Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating 500 mW 158°C/W -40°C to +85°C -65°C to +150°C 300°C 215°C 220°C >2 kV	14-Lead SOIC, Power Dissipation	650 mW
θJA, Thermal Impedance158°C/WOperating Temperature Range-40°C to +85°CIndustrial (A Version)-40°C to +85°CStorage Temperature Range-65°C to +150°CLead Temperature (Soldering, 10 s)300°CVapor Phase (60 s)215°CInfrared (15 s)220°CESD Rating>2 kV	θ_{JA} , Thermal Impedance	115°C/W
Operating Temperature Range Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating O 40°C to +85°C -65°C to +150°C 300°C 215°C 220°C >2 kV	16-Lead TSSOP, Power Dissipation	500 mW
Industrial (A Version) Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating -40°C to +85°C -65°C to +150°C 200°C 220°C >2 kV	θ_{JA} , Thermal Impedance	158°C/W
Storage Temperature Range Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating -65°C to +150°C 300°C 215°C 220°C >2 kV	Operating Temperature Range	
Lead Temperature (Soldering, 10 s) Vapor Phase (60 s) Infrared (15 s) ESD Rating 300°C 215°C 220°C 220°C >2 kV	Industrial (A Version)	−40°C to +85°C
Vapor Phase (60 s) 215°C Infrared (15 s) 220°C ESD Rating >2 kV	Storage Temperature Range	−65°C to +150°C
Infrared (15 s) 220°C ESD Rating >2 kV	Lead Temperature (Soldering, 10 s)	300°C
ESD Rating >2 kV	Vapor Phase (60 s)	215℃
222	Infrared (15 s)	220°C
EFT Rating (IEC1000-4-4) >1 kV	ESD Rating	>2 kV
	EFT Rating (IEC1000-4-4)	>1 kV

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

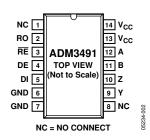


Figure 2. DIP/SOIC Pin Configuration

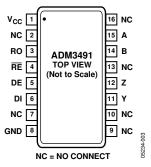


Figure 3. TSSOP Pin Configuration

Table 5. Pin Function Descriptions

Pin Number			
DIP/ SOIC TSSOP		Mnemonic	Description
1, 8	2, 7, 9, 10, 13, 16	NC	No Connect.
2	3	RO	Receiver Output. High when A > B by 200 mV; low when A < B by 200 mV.
3	4	RE	Receiver Output Enable. When $\overline{\text{RE}}$ is low, the receiver output RO is enabled. When $\overline{\text{RE}}$ is high, the output is high impedance. If $\overline{\text{RE}}$ is high and DE is low, the ADM3491 enters a shutdown state.
4	5	DE	Driver Output Enable. A high level enables the driver differential outputs, Y and Z. A low level places the part in a high impedance state.
5	6	DI	Driver Input. When the driver is enabled, a logic low on DI forces Y low and Z high; a logic high on DI forces Y high and Z low.
6, 7	8	GND	Ground Connection, 0 V.
9	11	Υ	Noninverting Driver Output Y.
10	12	Z	Inverting Driver Output Z.
11	14	В	Inverting Receiver Input B.
12	15	Α	Noninverting Receiver Input A.
13, 14	1	V cc	Power Supply, $3.3 \text{ V} \pm 0.3 \text{ V}$.

TEST CIRCUITS

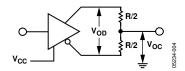


Figure 4. Driver Voltage Measurement Test Circuit

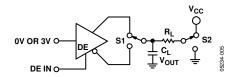


Figure 5. Driver Enable/Disable Test Circuit

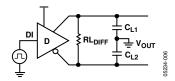


Figure 6. Driver Differential Output Delay Test Circuit

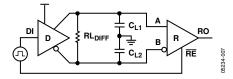


Figure 7. Driver/Receiver Propagation Delay Test Circuit

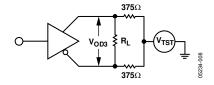


Figure 8. Driver Voltage Measurement Test Circuit 2

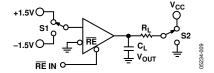


Figure 9. Receiver Enable/Disable Test Circuit

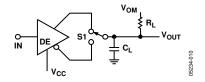


Figure 10. Driver Propagation Delay Test Circuit

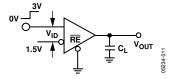


Figure 11. Receiver Propagation Delay Test Circuit

SWITCHING CHARACTERISTICS

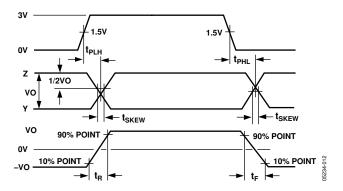


Figure 12. Driver Propagation Delay, Rise/Fall Timing

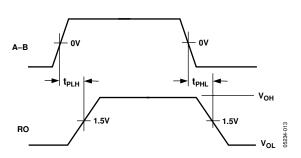


Figure 13. Receiver Propagation Delay

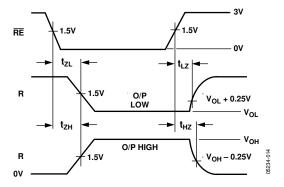


Figure 14. Driver Enable/Disable Timing

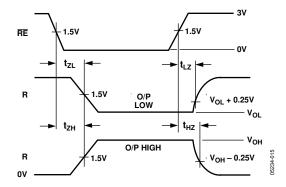


Figure 15. Receiver Enable/Disable Timing

TYPICAL PERFORMANCE CHARACTERISTICS

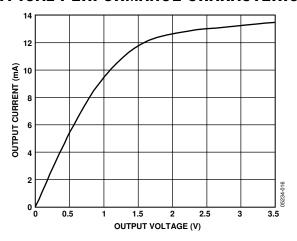


Figure 16. Receiver Output Low Voltage vs. Output Current

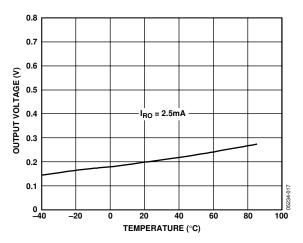


Figure 17. Receiver Output Low Voltage vs. Temperature

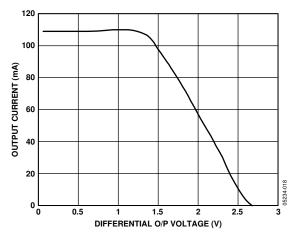


Figure 18. Driver Differential Output Voltage vs. Output Current

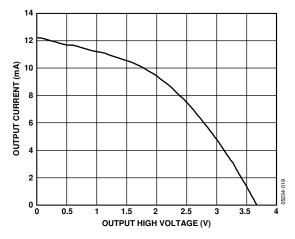


Figure 19. Receiver Output High Voltage vs. Output Current

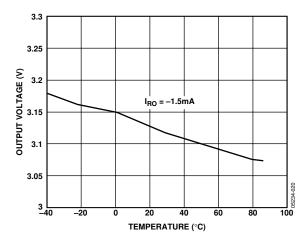


Figure 20. Receiver Output High Voltage vs. Temperature

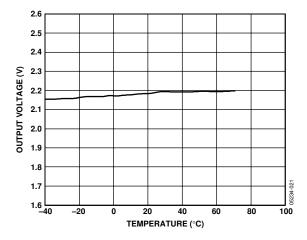


Figure 21. Driver Differential Output Voltage vs. Temperature

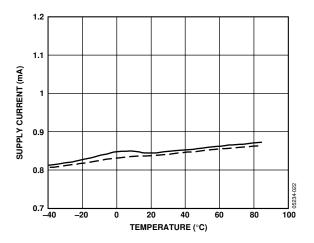


Figure 22. Supply Current vs. Temperature

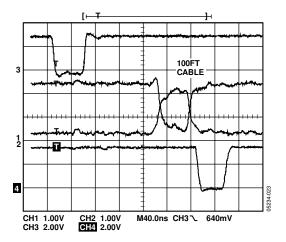


Figure 23. Driving 100 ft. Cable L-H Transition

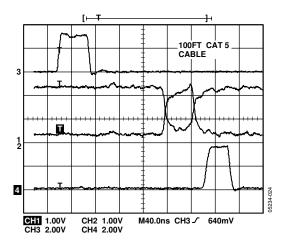


Figure 24. Driving 100 ft. Cable H-L Transition

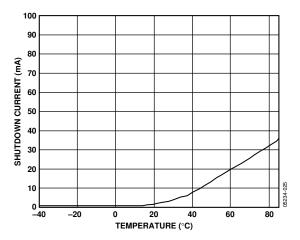


Figure 25. Shutdown Current vs. Temperature

APPLICATIONS INFORMATION

DIFFERENTIAL DATA TRANSMISSION

Differential data transmission is used to reliably transmit data at high rates over long distances and through noisy environments. Differential transmission nullifies the effects of ground shifts and noise signals, which appear as common-mode voltages on the line.

The two main standards approved by the Electronics Industries Association (EIA) specify the electrical characteristics of transceivers used in differential data transmission:

- RS-422 standard specifies data rates up to 10 MBaud and line lengths up to 4000 ft. A single driver can drive a transmission line with up to 10 receivers.
- RS-485 standard was defined to cater to true multipoint communications. This standard meets or exceeds all the requirements of RS-422, but also allows multiple drivers and receivers to be connected to a single bus. An extended common-mode range of -7 V to +12 V is defined.

The most significant differentiator of the RS-485 standard is that the drivers can be disabled, thereby allowing more than one to be connected to a single line. Only one driver should be enabled at a time, but the RS-485 standard contains additional specifications to guarantee device safety in the event of line contention.

Table 6. Comparison of RS-422 and RS-485 Interface Standards

Specification	RS-422	RS-485
Transmission Type	Differential	Differential
Maximum Cable Length	4000 ft.	4000 ft.
Minimum Driver Output Voltage	±2 V	±1.5 V
Driver Load Impedance	100 Ω	54 Ω
Receiver Input Resistance	4 kΩ min	12 kΩ min
Receiver Input Sensitivity	±200 mV	±200 mV
Receiver Input Voltage Range	−7 V to +7 V	−7 V to +12 V

CABLE AND DATA RATE

The transmission line of choice for RS-485 communications is a twisted pair. Twisted pair cable tends to cancel common-mode noise and also causes cancellation of the magnetic fields generated by the current flowing through each wire, thereby reducing the effective inductance of the pair.

The ADM3491 is designed for bidirectional data communications on multipoint transmission lines. A typical application showing a multipoint transmission network is illustrated in Figure 26. Only one driver can transmit at a particular time, but multiple receivers can be enabled simultaneously.

As with any transmission line, it is important that reflections be minimized. This can be achieved by terminating the extreme ends of the line using resistors equal to the characteristic impedance of the line. Stub lengths of the main line should also be kept as short as possible. A properly terminated transmission line appears purely resistive to the driver.

RECEIVER OPEN-CIRCUIT FAIL-SAFE FEATURE

The receiver input includes a fail-safe feature that guarantees a logic high on the receiver when the inputs are open circuit or floating.

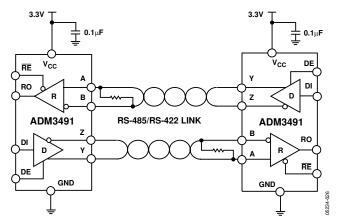


Figure 26. ADM3491 Full-Duplex Data Link

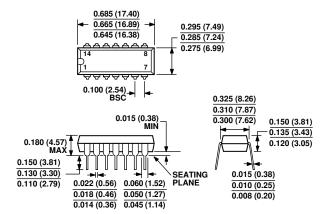
Table 7. Transmitting Truth Table

	Transmitting							
	Inputs	(Outputs					
RE	DE	DI	Z	Υ				
Χ	1	1	0	1				
Χ	1	0	1	0				
0	0	X	Hi-Z	Hi-Z				
1	0	Χ	Hi-Z	Hi-Z				

Table 8. Receiving Truth Table

	Receiving						
		Inpu	ts			Outp	uts
RE		DE		A-B		RO	
0		X		>+0.2 V		0	
0		Χ		< -0.2 V Inputs O/C		0	
0		Χ		Inputs O/C		1	
1		Χ		Χ		Hi-Z	

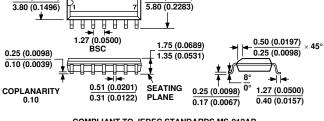
OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-095-AB
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

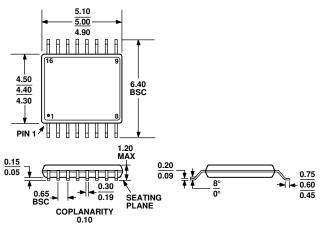
Figure 27. 14-Lead Plastic DIP (N-14) Dimensions shown in inches and (millimeters)

4.00 (0.1575) 3.80 (0.1496) 1.23 (0.0500) 4.00 (0.2283)



COMPLIANT TO JEDEC STANDARDS MS-012AB
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

Figure 28. 14-Lead Narrow Body Small Outline (SOIC) (R-14) Dimensions shown in inches and (millimeters)



COMPLIANT TO JEDEC STANDARDS MO-153AB

Figure 29. 16-Lead Thin Shrink Small Outline (TSSOP) (RU-16) Dimensions shown in inches and (millimeters)

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Options
ADM3491AN	-40°C to +85°C	14-Lead Plastic DIP	N-14
ADM3491AR	-40°C to +85°C	14-Lead Narrow Body Small Outline (SOIC)	R-14
ADM3491AR-REEL	-40°C to +85°C	14-Lead Narrow Body Small Outline (SOIC)	R-14
ADM3491AR-REEL7	-40°C to +85°C	14-Lead Narrow Body Small Outline (SOIC)	R-14
ADM3491ARZ ¹	-40°C to +85°C	14-Lead Narrow Body Small Outline (SOIC)	R-14
ADM3491ARZ-REEL ¹	-40°C to +85°C	14-Lead Narrow Body Small Outline (SOIC)	R-14
ADM3491ARZ-REEL7 ¹	-40°C to +85°C	14-Lead Narrow Body Small Outline (SOIC)	R-14
ADM3491ARU	-40°C to +85°C	16-Lead Thin Shrink Small Outline (TSSOP)	RU-16
ADM3491ARU-REEL	-40°C to +85°C	16-Lead Thin Shrink Small Outline (TSSOP)	RU-16
ADM3491ARU-REEL7	-40°C to +85°C	16-Lead Thin Shrink Small Outline (TSSOP)	RU-16
ADM3491ARUZ ¹	-40°C to +85°C	16-Lead Thin Shrink Small Outline (TSSOP)	RU-16
ADM3491ARUZ-REEL ¹	-40°C to +85°C	16-Lead Thin Shrink Small Outline (TSSOP)	RU-16
ADM3491ARUZ-REEL7 ¹	-40°C to +85°C	16-Lead Thin Shrink Small Outline (TSSOP)	RU-16

 $^{^{1}}$ Z = Pb-free part.

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ADM3491			
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